Rectifier Diode



DS5922-1.1 March 2009 (LN26638)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{DRM} V	Conditions
DS2906SA40 DS2906SA39 DS2906SA38 DS2906SA37 DS2906SA36 DS2906SA35	4000 3900 3800 3700 3600 3500	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DS2906SA39

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

V_{RRM} 4000V I_{F(AV)} 5651A I_{FSM} 83000A

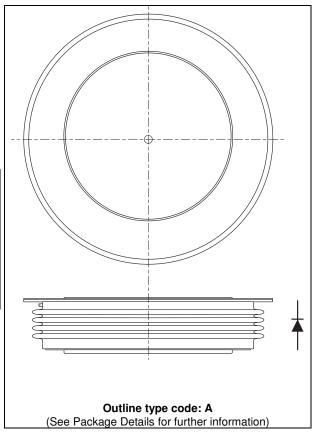


Fig. 1 Package outlines



CURRENT RATINGS

T_{case} = 75 °C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	5651	А			
I _{F(RMS)}	RMS value	-	8877	Α			
I _F	Continuous (direct) on-state current	-	8208	Α			
Single Sid	Single Side Cooled (Anode side)						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	3707	Α			
I _{F(RMS)}	RMS value	-	5821	Α			
I _F	Continuous (direct) on-state current	-	4976	Α			

T_{case} = 100 °C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	4350	Α			
I _{F(RMS)}	RMS value	-	6830	Α			
I _F	Continuous (direct) on-state current	-	6160	Α			
Single Side Cooled (Anode side)							
$I_{F(AV)}$	Mean forward current	Half wave resistive load	2795	Α			
I _{F(RMS)}	RMS value	-	4390	Α			
I _F	Continuous (direct) on-state current	-	3640	Α			



SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150 ℃	66.5	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4} \text{ sine}$	22	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150 ℃	83	kA
l ² t	I ² t for fusing	V _R = 0	34.5	MA ² s

THERMAL AND MECHANICAL RATINGS

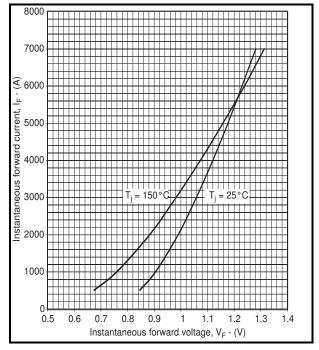
Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.0065	.c\M
		Single side cooled	Anode DC	-	0.013	.c\M
			Cathode DC	-	0.013	.c\M
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 83.0kN	Double side	-	0.001	%C/W
		(with mounting compound)	Single side	-	0.002	.c∖M
T_{vj}	Virtual junction temperature	On-state (conducting)		-	160	°
		Reverse (blocking)		-	150	°C
T _{stg}	Storage temperature range			-55	150	°C
Fm	Clamping force			75.0	91.0	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_{FM}	Forward voltage	At 3000A peak, T _{case} = 25 ℃	-	1.06	٧
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150 °C	-	400	mA
V _{TO}	Threshold voltage	At T _{vj} = 150 ℃	-	0.78	V
r _T	Slope resistance	At T _{vj} = 150 ℃	-	0.0763	mΩ



CURVES



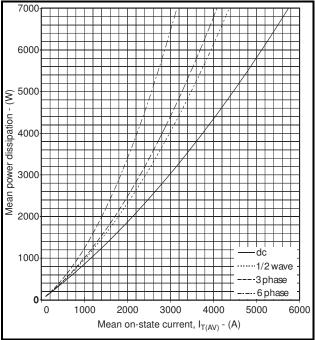


Fig.2 Maximum (limit) forward characteristics

Fig.3 Power loss curves

$V_{\text{TM}} \; \text{EQUATION}$

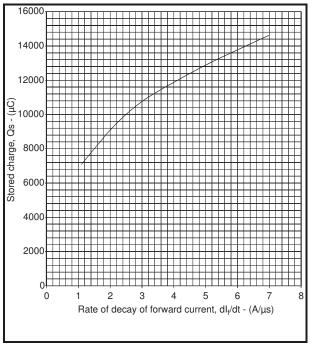
$$V_{TM} = A + BIn (I_T) + C.I_T + D.\sqrt{I_T}$$

Where A = -0.01591B = 0.113682

 $C = 8.04 \times 10^{-5}$ D = -0.00284

these values are valid for $T_j = 150$ °C for $I_F 500$ A to 7000A





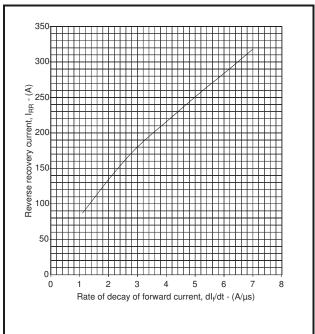


Fig.4 Stored charge

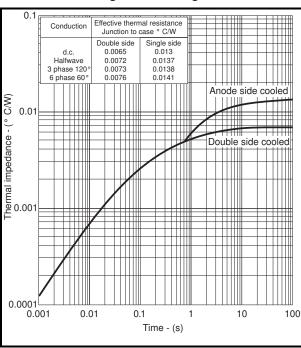


Fig.6 Maximum (limit) transient thermal impedance – junction to case

Fig.5 Reverse recovery current

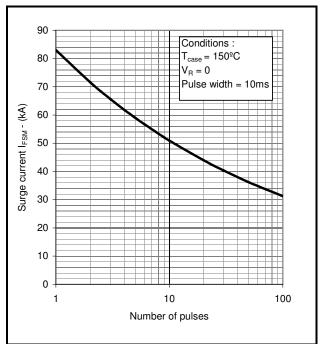


Fig.7 Multi-cycle surge current



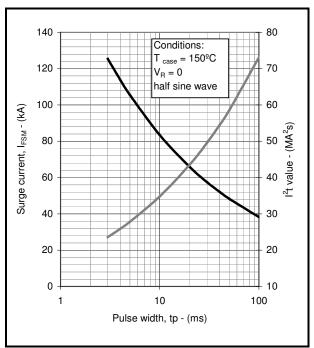
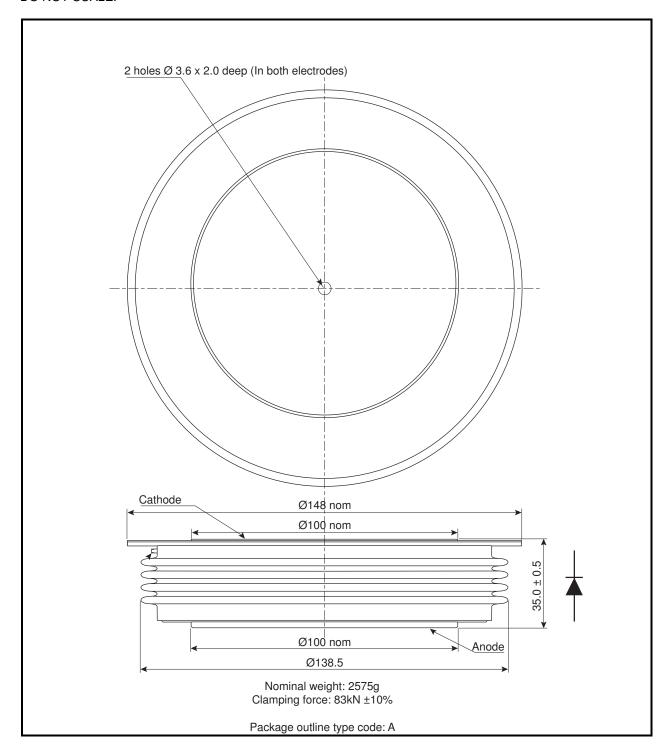


Fig.8 Sub-cycle surge current



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



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